



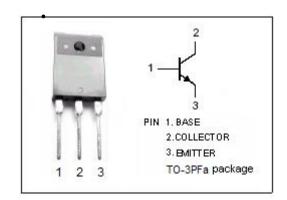
# **isc Silicon NPN Power Transistor**

## DESCRIPTION

- · Collector-Emilter Sustaining Voltage-
  - : V<sub>CEO(SUS)</sub>= 400V(Min.)
- · Low Collector Saturation Voltage
  - : V<sub>CE(sat)</sub>= 1.0V(Max.)@ I<sub>C</sub>= 5A
- · High Speed Switching

**APPLICATIONS** 

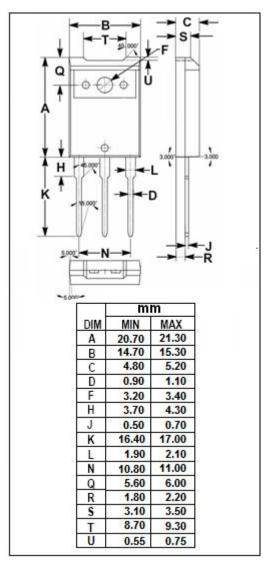
 Minimum Lot-to-Lot variations for robust device performance and reliable operation



Designed for high speed switching applications.

ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

| SYMBOL           | PARAMETER  | VALUE | UNIT         |  |
|------------------|--|-------|--------------|--|
| V <sub>CBO</sub> | Collector-Base Voltage                               | 500   | V            |  |
| V <sub>CEO</sub> | Collector-Emitter Voltage                            | 400   | V            |  |
| V <sub>EBO</sub> | Emitter-Base Voltage                                 | 7     | V            |  |
| Ic               | Collector Current-Continuous                         | 10    | А            |  |
| I <sub>CM</sub>  | Collector Current-Peak                               | 20    | А            |  |
| lв               | Base Current-Continuous                              | 5     | А            |  |
| Pc               | Collector Power Dissipation<br>@T <sub>a</sub> =25°C | 3     | - W          |  |
|                  | Collector Power Dissipation<br>@T <sub>C</sub> =25°C | 100   |              |  |
| Tj               | Junction Temperature                                 | 150   | $^{\circ}$ C |  |
| T <sub>stg</sub> | Storage Temperature Range -55~1                      |       | $^{\circ}$   |  |





## isc Silicon NPN Power Transistor

2SC3210

## **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

| 1c-25 C unless otherwise specified |                                      |   |     |      |     |      |  |  |  |
|------------------------------------|--------------------------------------|---|-----|------|-----|------|--|--|--|
| SYMBOL                             | PARAMETER                            | CONDITIONS  | MIN | TYP. | MAX | UNIT |  |  |  |
| V <sub>CEO(SUS)</sub>              | Collector-Emitter Sustaining Voltage | I <sub>C</sub> = 30mA; I <sub>B</sub> =0  | 400 |      |     | V    |  |  |  |
| V <sub>CE(sat)</sub>               | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 5A; I <sub>B</sub> = 1A  |     |      | 1.0 | V    |  |  |  |
| V <sub>BE(sat)</sub>               | Base-Emitter Saturation Voltage      | I <sub>C</sub> = 5A; I <sub>B</sub> = 1A  |     |      | 1.5 | V    |  |  |  |
| I <sub>CBO</sub>                   | Collector Cutoff Current             | V <sub>CB</sub> = 500V; I <sub>E</sub> = 0  |     |      | 0.1 | mA   |  |  |  |
| I <sub>EBO</sub>                   | Emitter Cutoff Current               | V <sub>EB</sub> = 5V; I <sub>C</sub> = 0  |     |      | 0.1 | mA   |  |  |  |
| h <sub>FE-1</sub>                  | DC Current Gain                      | I <sub>C</sub> = 0.1A; V <sub>CE</sub> = 5V   | 15  |      |     |      |  |  |  |
| h <sub>FE-2</sub>                  | DC Current Gain                      | I <sub>C</sub> = 5A; V <sub>CE</sub> = 5V   | 8   |      |     |      |  |  |  |
| f <sub>T</sub>                     | Current-Gain—Bandwidth Product       | I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 10V  |     | 11   |     | MHz  |  |  |  |
| Switching Times; Resistive Load    |                                      |   |     |      |     |      |  |  |  |
| t <sub>on</sub>                    | Turn-on Time                         |   |     |      | 1.0 | μ \$ |  |  |  |
| ts                                 | Storage Time                         | I <sub>C</sub> = 5A; I <sub>B1</sub> = -I <sub>B2</sub> = 1A;<br>V <sub>CC</sub> = 100V |     |      | 2.5 | μS   |  |  |  |
| tf                                 | Fall Time                            |   |     |      | 1.0 | μS   |  |  |  |

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